

Effects of energy dependence in the electronic density of states on the far-infrared absorption in superconductors

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Allen's theory of far-infrared absorption in superconductors is generalized to the case when the electronic density of states, $N(\epsilon)$, cannot be taken as constant in the vicinity of the Fermi level. Such a situation can arise in several of the $A15$ compounds. Numerical calculations show that $N(\epsilon) \neq \text{const}$ can yield an additional frequency dependence in the absorption spectrum.

I. INTRODUCTION

One of the features of several $A15$ superconductors, such as V_3Si , V_3Ga , and Nb_3Sn , is a rapidly varying electronic density of states, $N(\epsilon)$, in the vicinity of the chemical potential $\epsilon=0$. With $[1/N(\epsilon)]dN(\epsilon)/d\epsilon = O(1/\Omega_{\text{max}})$ near $\epsilon=0$, where Ω_{max} is the maximum phonon frequency, it is expected that the energy dependence in $N(\epsilon)$ would influence experiments which measure the electron-phonon (EP) coupling function $\alpha^2(\Omega)F(\Omega)$. Indeed, detailed calculations^{1,2} have shown that an ϵ dependence of $N(\epsilon)$, which is found in the band-structure calculations, affects the results of tunneling experiments. Unfortunately, the tunneling experiments on $A15$ superconductors are often influenced by the proximity effect due to degraded superconducting properties within a first few atomic layers of the $A15$ electrode near the tunneling barrier.³⁻⁶ At the present time it is not possible to separate the effects of nonconstant $N(\epsilon)$ from the influence of the proximity effect on tunneling characteristics.

Far-infrared absorption measurements can also be utilized to determine the EP coupling function of a metal.⁷⁻⁹ These experiments probe the sample through a skin depth (which is about 100 nm for $A15$ materials) and, therefore, are less sensitive to the state of the surface than the tunneling experiments, which probe the sample through a coherence length (which is about 5 nm for the high superconducting T_c $A15$ compounds¹⁰). In a recent paper¹¹ it has been shown that the far-infrared transmis-

sion measurements on a thin film of normal V_3Si (Ref. 9) can be explained with a transport EP coupling function $\alpha_{tr}^2 F$ which is consistent with the neutron scattering results,¹² only by invoking an energy dependent $N(\epsilon)$. Farnworth and Timusk⁸ have shown that more direct information about $\alpha_{tr}^2 F$ can be obtained by combining the far-infrared absorption measurements in both the normal and the superconducting states, within Allen's golden-rule theory.⁷ In the present work, we extend a study of the effect of nonconstant $N(\epsilon)$ on infrared behavior to the superconducting state.

In Sec. II we generalize Allen's theory to include $N(\epsilon) \neq \text{const}$. In Sec. III we present the results of our numerical calculations with a discussion and Sec. IV contains conclusions.

II. THEORY

The effect of EP and electron-impurity (EI) collisions on the ac conductivity $\sigma(\mathbf{q}, \omega)$, at the wave vector \mathbf{q} and frequency ω , can be obtained from the equation (throughout this paper we take $\hbar=1$)

$$|\mathbf{E}|^2 \text{Re}\sigma(\mathbf{q}, \omega) = \omega \Gamma(\mathbf{q}, \omega),$$

which relates the rate of energy dissipation by the electric field \mathbf{E} to the transition probability per unit time $\Gamma(\mathbf{q}, \omega)$ calculated within the golden rule. In this way, Allen⁷ has obtained the expressions for EP and EI scattering contributions to the conductivity in the superconducting state:

$$\text{Re}\sigma_{s,\text{ph}}(\omega) = \frac{\pi e^2}{3\omega^3} \sum_{\mathbf{k}, \mathbf{k}'} |g_{\mathbf{k}\mathbf{k}'}|^2 (\mathbf{v}_{\mathbf{k}} - \mathbf{v}_{\mathbf{k}'})^2 \frac{1}{2} \left[1 - \frac{\epsilon_{\mathbf{k}}\epsilon_{\mathbf{k}'} - \Delta_{\mathbf{k}}\Delta_{\mathbf{k}'}}{E_{\mathbf{k}}E_{\mathbf{k}'}} \right] \delta(E_{\mathbf{k}} + E_{\mathbf{k}'} + \Omega_{\mathbf{k}-\mathbf{k}'} - \omega), \tag{1}$$

$$\text{Re}\sigma_{s,i}(\omega) = \frac{\pi e^2}{3\omega^3} \sum_{\mathbf{k}, \mathbf{k}'} n_i |V_{\mathbf{k}\mathbf{k}'}|^2 (\mathbf{v}_{\mathbf{k}} - \mathbf{v}_{\mathbf{k}'})^2 \frac{1}{2} \left[1 - \frac{\epsilon_{\mathbf{k}}\epsilon_{\mathbf{k}'} - \Delta_{\mathbf{k}}\Delta_{\mathbf{k}'}}{E_{\mathbf{k}}E_{\mathbf{k}'}} \right] \delta(E_{\mathbf{k}} + E_{\mathbf{k}'} - \omega). \tag{2}$$

In Eqs. (1) and (2) e is the electron charge, \mathbf{k} labels the Bloch states, $g_{\mathbf{k}\mathbf{k}'}$ ($V_{\mathbf{k}\mathbf{k}'}$) is the EP (EI) scattering matrix element, $\mathbf{v}_{\mathbf{k}}$ ($\epsilon_{\mathbf{k}}$) is the electron velocity (band energy), n_i is the impurity concentration, $\Omega_{\mathbf{Q}}$ is the phonon energy, and

$$E_{\mathbf{k}} = \left[\epsilon_{\mathbf{k}}^2 + \Delta_{\mathbf{k}}^2 \right]^{1/2}, \tag{3}$$

where $\Delta_{\mathbf{k}}$ is the superconducting energy gap.

By using a set of coordinates in which electron energy ϵ is one of the coordinates and by ignoring the anisotropy effects, Eq. (1) can be rewritten in the form

$$\text{Re}\sigma_{s,\text{ph}}(\omega) = \frac{1}{8\omega^3} \int_{-\infty}^{+\infty} d\epsilon \int_{-\infty}^{+\infty} d\epsilon' \left[\frac{N(\epsilon)}{N(0)} \Omega_p^2(\epsilon') + \frac{N(\epsilon')}{N(0)} \Omega_p^2(\epsilon) \right] \frac{1}{2} \left[1 - \frac{\epsilon\epsilon' - \Delta^2}{E(\epsilon)E(\epsilon')} \right] \alpha_{\text{tr}}^2 F(\omega - E(\epsilon) - E(\epsilon')), \quad (4)$$

where

$$\Omega_p^2(\epsilon) = \frac{8\pi N(\epsilon)v^2(\epsilon)e^2}{3} \quad (5)$$

is the square of the Drude plasma frequency,

$$N(\epsilon) = \sum_{\mathbf{k}} \delta(\epsilon - \epsilon_{\mathbf{k}}) \quad (6)$$

is the single-spin-band density of states, and

$$v^2(\epsilon) = \sum_{\mathbf{k}} v_{\mathbf{k}}^2 \delta(\epsilon - \epsilon_{\mathbf{k}}) / N(\epsilon). \quad (7)$$

Also, the transport electron-phonon coupling function is defined by

$$\alpha_{\text{tr}}^2(\Omega)F(\Omega) = N(0) \sum_{\mathbf{k}, \mathbf{k}'} |g_{\mathbf{k}\mathbf{k}'}|^2 (v_{\mathbf{k}} - v_{\mathbf{k}'})^2 \delta(\Omega - \Omega_{\mathbf{k}-\mathbf{k}'}) \delta(\epsilon - \epsilon_{\mathbf{k}}) \delta(\epsilon' - \epsilon_{\mathbf{k}'}) \left[\sum_{\mathbf{k}, \mathbf{k}'} (v_{\mathbf{k}} - v_{\mathbf{k}'})^2 \delta(\epsilon - \epsilon_{\mathbf{k}}) \delta(\epsilon' - \epsilon_{\mathbf{k}'}) \right]^{-1}, \quad (8)$$

where the (ϵ, ϵ') dependence of the right-hand side is assumed to be negligible.

Now, we will use the fact, established in band-structure calculations for *A* 15 compounds,¹³ that the ϵ dependence of $\Omega_p^2(\epsilon)$ can be ignored compared to the ϵ dependence of $N(\epsilon)$ in the vicinity of $\epsilon=0$. Then Eq. (4) reduces to

$$\text{Re}\sigma_{s,\text{ph}}(\omega) = \frac{\Omega_p^2}{4\pi\omega} \frac{1}{\omega} \frac{1}{\tau_{s,\text{ph}}(\omega)}, \quad (9)$$

where

$$\begin{aligned} \frac{1}{\tau_{s,\text{ph}}(\omega)} &= \frac{2\pi}{\omega} \int_{-\infty}^{+\infty} d\epsilon \int_{-\infty}^{+\infty} d\epsilon' \frac{1}{2} \left[\frac{N(\epsilon)}{N(0)} + \frac{N(\epsilon')}{N(0)} \right] \\ &\quad \times \frac{1}{4} \left[1 - \frac{\epsilon\epsilon' - \Delta^2}{(\epsilon^2 + \Delta^2)^{1/2}(\epsilon'^2 + \Delta^2)^{1/2}} \right] \alpha_{\text{tr}}^2 F(\omega - (\epsilon^2 + \Delta^2)^{1/2} - (\epsilon'^2 + \Delta^2)^{1/2}). \end{aligned} \quad (10)$$

After some algebra, Eq. (10) can be rewritten in the form

$$\frac{1}{\tau_{s,\text{ph}}(\omega)} = \frac{2\pi}{\omega} \int_0^{\omega-2\Delta} d\Omega (\omega - \Omega) \alpha_{\text{tr}}^2(\Omega) F(\Omega) D \left[\frac{2\Delta}{\omega - \Omega} \right], \quad (11)$$

where

$$\begin{aligned} D(a) &\equiv \int_0^1 dx \left\{ (1+a) \frac{\left[1 - \left[\frac{1-a}{1+a} \right]^2 x^2 \right]^{1/2}}{(1-x^2)^{1/2}} - 2 \frac{a}{1+a} \frac{1}{(1-x^2)^{1/2} \left[1 - \left[\frac{1-a}{1+a} \right]^2 x^2 \right]^{1/2}} \right\} \\ &\quad \times \frac{1}{2} \left[\frac{1}{2} \left[\frac{N \left[\frac{\Delta}{a} (1-a^2)^{1/2} \left[(1-x) \left[1 - \frac{1-a}{1+a} x \right] \right]^{1/2}}{N(0)} \right]}{N(0)} + \frac{N \left[-\frac{\Delta}{a} (1-a^2)^{1/2} \left[(1-x) \left[1 - \frac{1-a}{1+a} x \right] \right]^{1/2}}{N(0)} \right]}{N(0)} \right] \right. \\ &\quad \left. + \frac{1}{2} \left[\frac{N \left[\frac{\Delta}{a} (1-a^2)^{1/2} \left[(1+x) \left[1 + \frac{1-a}{1+a} x \right] \right]^{1/2}}{N(0)} \right]}{N(0)} + \frac{N \left[-\frac{\Delta}{a} (1-a^2)^{1/2} \left[(1+x) \left[1 + \frac{1-a}{1+a} x \right] \right]^{1/2}}{N(0)} \right]}{N(0)} \right] \right\} \quad (12) \end{aligned}$$

with $|a| \leq 1$. In the case when $N(\epsilon) = \text{const}$,

$$D(a) = E(1 - a^2),$$

where

$$E(m) = \int_0^1 dx \frac{(1 - mx^2)^{1/2}}{(1 - x^2)^{1/2}}$$

is the complete elliptic integral of the second kind, and Eq. (11) reduces to Allen's result.⁷

In an analogous manner, one gets for the impurity conductivity

$$\text{Re}\sigma_{s,i}(\omega) = \frac{\Omega_p^2}{4\pi\omega} \frac{1}{\omega} \frac{1}{\tau_{s,i}(\omega)}, \quad (13)$$

where

$$\frac{1}{\tau_{s,i}(\omega)} = \frac{1}{\tau_i} D\left[\frac{2\Delta}{\omega}\right] \quad (14)$$

and

$$\frac{1}{\tau_i} = \pi n_i N(0) \sum_{\mathbf{k}, \mathbf{k}'} |V_{\mathbf{k}, \mathbf{k}'}|^2 (\mathbf{v}_{\mathbf{k}} - \mathbf{v}_{\mathbf{k}'})^2 \delta(\epsilon_{\mathbf{k}}) \delta(\epsilon_{\mathbf{k}'}) \times \left[\sum_{\mathbf{k}, \mathbf{k}'} (\mathbf{v}_{\mathbf{k}} - \mathbf{v}_{\mathbf{k}'})^2 \delta(\epsilon_{\mathbf{k}}) \delta(\epsilon_{\mathbf{k}'}) \right]^{-1}. \quad (15)$$

Equation (14) reduces to Allen's result⁷ when $N(\epsilon) = \text{const}$. In the normal state one gets

$$\text{Re}\sigma_{N,\text{ph}}(\omega) = \frac{\Omega_p^2}{4\pi\omega} \frac{1}{\omega} \frac{1}{\tau_{N,\text{ph}}(\omega)}, \quad (16)$$

$$\frac{1}{\tau_{N,\text{ph}}(\omega)} = \frac{2\pi}{\omega} \int_0^\omega d\Omega \alpha_{\text{tr}}^2(\Omega) F(\Omega) \times \int_0^{\omega-\Omega} d\epsilon \left[\frac{1}{2} \left[\frac{N(\epsilon)}{N(0)} + \frac{N(-\epsilon)}{N(0)} \right] \right], \quad (17)$$

$$\text{Re}\sigma_{N,i}(\omega) = \frac{\Omega_p^2}{4\pi\omega} \frac{1}{\omega} \frac{1}{\tau_{N,i}(\omega)}, \quad (18)$$

$$\frac{1}{\tau_{N,i}(\omega)} = \frac{1}{\tau_i} \frac{1}{\omega} \int_0^\omega d\epsilon \left[\frac{1}{2} \left[\frac{N(\epsilon)}{N(0)} + \frac{N(-\epsilon)}{N(0)} \right] \right]. \quad (19)$$

Again, expressions (17) and (19) reduce to Allen's results for the normal state when $N(\epsilon) = \text{const}$.

It is not difficult to show that

$$\int_0^{+\infty} d\omega \text{Re}\sigma_{N,\text{ph}}(\omega) = \frac{\Omega_p^2}{8} \lambda_{\text{tr}}, \quad (20)$$

with

$$\lambda_{\text{tr}} = \bar{\lambda}_{\text{EP}}(\omega=0) \quad (21)$$

and

$$\bar{\lambda}_{\text{EP}}(\omega) = 2 \int_0^{\Omega_{\text{max}}} \frac{d\Omega}{\Omega} \alpha_{\text{tr}}^2(\Omega) F(\Omega) \times \int_0^{+\infty} d\epsilon \frac{1}{2} \left[\frac{N(\epsilon)}{N(0)} + \frac{N(-\epsilon)}{N(0)} \right] \times \frac{\Omega}{\omega^2} \ln \left| \frac{(\epsilon + \Omega)^2}{(\epsilon + \Omega)^2 - \omega^2} \right|. \quad (22)$$

We point out that $\bar{\lambda}_{\text{EP}}$ is related to $1/\tau_{N,\text{ph}}(\omega)$ by the Hilbert transform

$$\omega \bar{\lambda}_{\text{EP}}(\omega) = \frac{1}{\pi} \int_{-\infty}^{+\infty} d\omega' \frac{1/\tau_{N,\text{ph}}(\omega')}{\omega' - \omega}. \quad (23)$$

As noted by Allen,⁷ result (20) implies that the total conductivity $\sigma_{\text{tot}}(\mathbf{q}, \omega)$ (collisionless plus EP) can be made to satisfy the f sum rule,

$$\int_0^{+\infty} d\omega \text{Re}\sigma_{\text{tot}}(\mathbf{q}, \omega) = \frac{\Omega_p^2}{8}, \quad (24)$$

if Ω_p^2 in the expressions for both the collisionless and the electron-phonon conductivity is replaced by

$$(\Omega_p^*)^2 = \Omega_p^2 / (1 + \lambda_{\text{tr}}). \quad (25)$$

This *ad hoc* procedure makes the results of the golden-rule theory closer to the results of a more rigorous treatment^{7,14} which is based on Holstein's theory.¹⁵ The latter gives for the local ($\mathbf{q}=0$) conductivity in the normal state¹⁴

$$\sigma(\omega) = \frac{\Omega_p^2 / [1 + \bar{\lambda}(\omega)]}{4\pi} \frac{\tau^*(\omega)}{1 - i\omega\tau^*(\omega)}, \quad (26)$$

where

$$\frac{1}{\tau^*(\omega)} = \frac{1/\tau_{N,\text{ph}}(\omega) + 1/\tau_{N,i}(\omega)}{1 + \bar{\lambda}(\omega)}, \quad (27)$$

with $1/\tau_{N,\text{ph}}$ and $1/\tau_{N,i}$ given by Eqs. (17) and (19) and

$$\bar{\lambda}(\omega) = \bar{\lambda}_{\text{EP}}(\omega) + \bar{\lambda}_i(\omega), \quad (28)$$

where $\bar{\lambda}_{\text{EP}}(\omega)$ is given by Eq. (22) and

$$\bar{\lambda}_i(\omega) = \frac{1}{\pi\tau_i\omega} \int_0^\infty d\epsilon \left[\frac{1}{2} \left[\frac{N(\epsilon)}{N(0)} + \frac{N(-\epsilon)}{N(0)} \right] \ln \left| \frac{\epsilon^2}{\epsilon^2 - \omega^2} \right| \right]. \quad (29)$$

The golden-rule result for the normal-state conductivity due to collisions (EP plus EI)

$$\text{Re}\sigma_N(\omega) = \frac{\Omega_p^2}{4\pi\omega} \frac{1}{\omega} \frac{1}{\tau_N(\omega)}, \quad (30)$$

$$1/\tau_N(\omega) = 1/\tau_{N,\text{ph}}(\omega) + 1/\tau_{N,i}(\omega), \quad (31)$$

can be cast into a form resembling the lowest-order term in the expansion of (26) into the powers of $(\omega\tau^*)^{-1}$. This can be done by replacing Ω_p^2 with $(\Omega_p^*)^2$, Eq. (25) with $\bar{\lambda}(\omega)$ instead of λ_{tr} , and by renormalizing $1/\tau_N(\omega)$ by $[1 + \bar{\lambda}(\omega)]$, i.e.,

$$1/\tau_N(\omega) \rightarrow [1/\tau_N(\omega)]/[1+\bar{\lambda}(\omega)] . \quad (32)$$

An analysis¹⁴ of Holstein's theory also indicates that $N(\epsilon)$ in the equations for $1/\tau_{N,\text{ph}}$ and $1/\tau_{N,i}$ should be interpreted as the quasiparticle density of states

$$N(\epsilon) = -\frac{1}{\pi} \text{Im} \sum_{\mathbf{k}} G(\mathbf{k}, \epsilon + i0^+) , \quad (33)$$

where G is the electron Green's function. This density of states includes the self-energy effects, i.e., the lifetime broadening and the energy renormalization, and can be quite different from its bare band-electron counterpart $N_0(\epsilon)$ when $N_0(\epsilon) \neq \text{const}$ near $\epsilon=0$ (Ref. 16).

Following Allen,⁷ the volume absorption $A_{N,v}$ in the normal state can be written as

$$A_{N,v} = A_{\text{tot}} - A_s = \Phi_N(\omega) \frac{2}{\Omega_p} \frac{1}{\tau_N(\omega)} , \quad (34a)$$

or as

$$A_{N,v} = A_{\text{tot}} - A_s = \Phi_N(\omega) \frac{2}{\Omega_p} \frac{1}{\tau_N(\omega)} \frac{1}{[1+\bar{\lambda}(\omega)]^{1/2}} , \quad (34b)$$

where A_{tot} and A_s are the total and the surface absorption, respectively, and $\Phi_N(\omega)$ is a weakly varying function of frequency. Equation (34a) is the golden-rule-theory result, while Eq. (34b) is a modification of (34a) which includes some strong-coupling corrections.

In the case of the superconducting state, the golden-rule theory gives for the volume absorption

$$A_{s,v} = \Phi_s(\omega) \frac{2}{\Omega_p} \frac{1}{\tau_s(\omega)} , \quad (35a)$$

while the result which is analogous to (34b) would be

$$A_{s,v} = \Phi_s(\omega) \frac{2}{\Omega_p} \frac{1}{\tau_s(\omega)} \frac{1}{[1+\bar{\lambda}(\omega)]^{1/2}} , \quad (35b)$$

where

$$1/\tau_s(\omega) = 1/\tau_{s,\text{ph}}(\omega) + 1/\tau_{s,i}(\omega) ,$$

with $1/\tau_{s,\text{ph}}$ and $1/\tau_{s,i}$ given by Eqs. (11) and (14), and where $\Phi_s(\omega)$ is a weakly varying function of ω . However, in contrast to the normal-state case, Eq. (35b) could not be justified from the strong-coupling theory and is really an ansatz based on the fact that $A_{s,v}$ should become equal to $A_{N,v}$ when $\Delta \rightarrow 0$. In fact, one can expect that instead of using $\bar{\lambda}(\omega)$ in Eq. (35b) one should use a different renormalization parameter $\bar{\lambda}_s(\omega)$. On the basis of the difference between the mass renormalization parameters in the normal and the superconducting states, it is expected that $\bar{\lambda}_s - \bar{\lambda} = O((\Delta/\Omega_{\text{max}})^2 \ln(\Delta/\Omega_{\text{max}}))$ (Ref. 17).

Finally we point out that $N(\epsilon)$ in the equations for $1/\tau_{s,\text{ph}}$ and $1/\tau_{s,i}$ will also be interpreted as the *normal-state* quasiparticle density of states. There is no basis for this assumption within the golden-rule theory. It is only the requirement $A_{s,v} \rightarrow A_{N,v}$ as $\Delta \rightarrow 0$ that perhaps justifies such an interpretation of $N(\epsilon)$. Also, one intuitively expects that the effects of the lifetime broadening, due to impurity scattering, etc., should be contained in the theory.

III. NUMERICAL RESULTS AND DISCUSSION

Farnworth and Timusk⁸ have shown that detailed information about the electron-phonon coupling function $\alpha_{\text{tr}}^2 F$ is contained in the derivative $S'(\omega)$ of the difference between the absorption in the superconducting state and the normal-state absorption:

$$S'(\omega) = dS(\omega)/d\omega , \quad (36)$$

$$S(\omega) = A_{s,v} - A_{N,v} . \quad (37)$$

Within Allen's golden-rule theory for $N(\epsilon) = \text{const}$ one has

$$S'(\omega) = \frac{4\pi^2 \Delta}{\Omega_p \omega} \alpha_{\text{tr}}^2 F(\omega - 2\Delta) + \frac{4\pi}{\omega^2 \Omega_p} \int_0^{\omega-2\Delta} d\Omega \alpha_{\text{tr}}^2(\Omega) F(\Omega) \left[\Omega E(k^2) + \omega \frac{1-k^2}{k^2} [E(k^2) - K(k^2)] \right] - \frac{4\pi}{\omega^2 \Omega_p} \int_0^{\omega} d\Omega \Omega \alpha_{\text{tr}}^2(\Omega) F(\Omega) + \frac{1}{\tau_i} \frac{2}{\omega \Omega_p} \frac{1-k'^2}{k'^2} [E(k'^2) - K(k'^2)] , \quad (38)$$

where

$$k'^2 = 1 - \left[\frac{2\Delta}{\omega} \right]^2 , \quad (39a)$$

$$k^2 = 1 - \left[\frac{2\Delta}{\omega - \Omega} \right]^2 , \quad (39b)$$

and

$$K(m) = \int_0^1 dx \frac{1}{(1-x^2)^{1/2} (1-mx^2)^{1/2}} . \quad (40)$$

Also, two weakly varying functions, $\Phi_s(\omega)$ and $\Phi_N(\omega)$, are assumed to be constant and equal to their high-

frequency value of 1.

Although Eq. (38) is expected to work better for the weak-coupling superconductors than for the strong couplers like Pb, Farnworth and Timusk have demonstrated that Eq. (38) describes their high-resolutions measurements on Pb quite well. Moreover they have solved the integral equation (38) for $\alpha_{\text{tr}}^2 F$ with the experimental $S'(\omega)$. The inverted $\alpha_{\text{tr}}^2 F$ spectrum was in good agreement with the $\alpha^2 F$ function for Pb, measured in the tunneling experiments.

Our program for studying the effects of nonconstant $N(\epsilon)$ on the far-infrared absorption is as follows. First we calculate $S'(\omega)$ for an $N(\epsilon) \neq \text{const}$ by using the theory described in Sec. II and compare that $S'(\omega)$ with the cor-

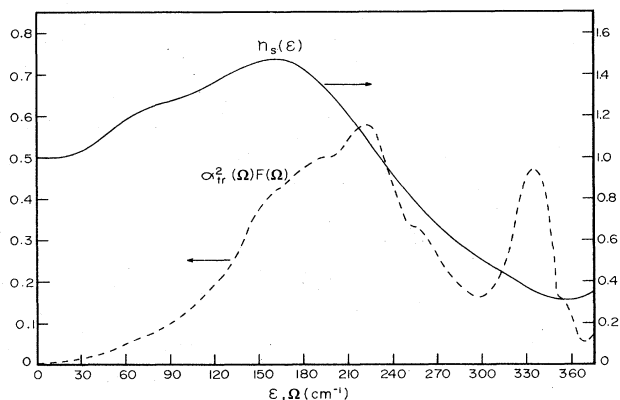


FIG. 1. Symmetrized density of states $n_s(\epsilon)$ and $\alpha_{tr}^2(\Omega)F(\Omega)$ which are used in the numerical work.

responding quantity calculated for $N(\epsilon)=\text{const}$. Second, we invert $S'(\omega)$ obtained for nonconstant $N(\epsilon)$, assuming that the usual theory [$N(\epsilon)=\text{const}$] is applicable, i.e., we solve Eq. (38) for α_{tr}^2F . The resulting effective coupling function $(\alpha_{tr}^2F)_{\text{eff}}$ may differ from the true α_{tr}^2F if the effects of nonconstant $N(\epsilon)$ are important. In our numerical calculations we use the EP coupling spectrum α_{tr}^2F and the symmetrized density of states

$$n_s(\epsilon) = \frac{1}{2} \left[\frac{N(\epsilon)}{N(0)} + \frac{N(-\epsilon)}{N(0)} \right] \quad (41)$$

(Fig. 1) which were used to fit the normal-state far-infrared transmission data on thin film of V_3Si (Ref. 11).

In Fig. 2 we show $S'(\omega)$ calculated for $1/\tau_i = 296 \text{ cm}^{-1}$ (Ref. 11), $\Omega_p = 3 \text{ eV}$ (Ref. 18), and $2\Delta = 45 \text{ cm}^{-1}$ (Ref. 19). Note that a different choice for Ω_p would only change the vertical scale in Fig. 2. In generating $S'(\omega)$ we have used the unrenormalized expressions (34a) and (35a) for $A_{N,v}$ and $A_{s,v}$ respectively. Also, the weakly varying functions $\Phi_s(\omega)$ and $\Phi_N(\omega)$ are assumed to be constant and equal to their high-frequency value of 1. The work of Farnworth and Timusk⁸ indicates that both of these ap-

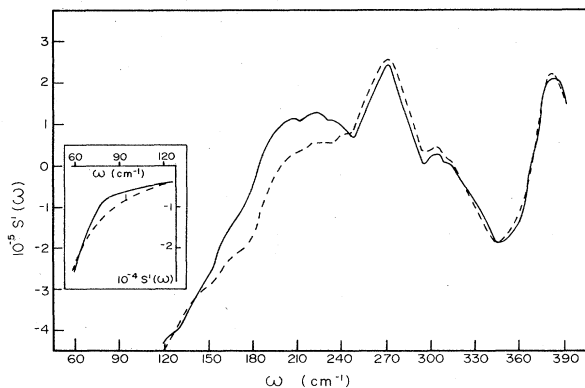


FIG. 2. Derivative of the absorption spectrum. Solid line is calculated using $n_s(\epsilon)$ from Fig. 1 and the dashed line is calculated using $n_s(\epsilon)=1$. The inset shows the extension of the two curves to lower frequencies.

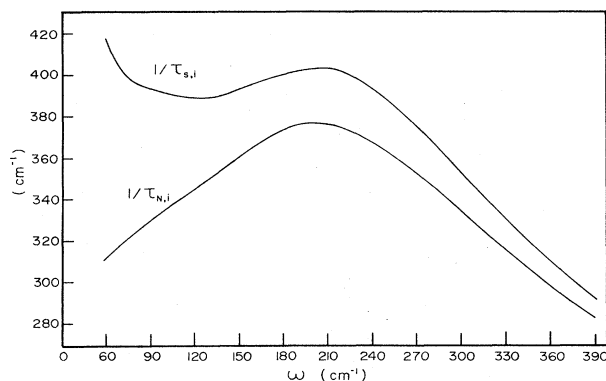


FIG. 3. Impurity scattering times for the superconducting and the normal states.

proximations are reasonable. Later on we will examine the effect of the renormalization factor $[1 + \bar{\lambda}(\omega)]^{-1/2}$ on $S'(\omega)$.

The difference between $S'(\omega)$ calculated for nonconstant $N(\epsilon)$ (solid line in Fig. 2) and the one calculated for $N(\epsilon)=\text{const}$ (dashed line in Fig. 2) is mainly due to impurity contribution via $1/\tau_{s,i}$ and $1/\tau_{N,i}$, Fig. 3. $S'(\omega)$ calculated by leaving out the impurity scattering did not depend much on the structure in $N(\epsilon)$.

The $S'(\omega)$ data for nonconstant $N(\epsilon)$ were inverted by solving Eq. (38) for α_{tr}^2F . The resulting effective spectrum $(\alpha_{tr}^2F)_{\text{eff}}$ is shown in Fig. 4 (solid line) together with the true input spectrum (dashed line). There is a transfer of weight in $(\alpha_{tr}^2F)_{\text{eff}}$ to lower frequencies as compared to α_{tr}^2F . A similar behavior was found in the study of the influence of a peak in $N(\epsilon)$ around the Fermi level on superconductive tunneling.^{1,2} We note, however, that in the case of infrared absorption this effect is dominated by the impurity scattering, while in the case of tunneling the transfer of weight in $(\alpha^2F)_{\text{eff}}$ was obtained without explicitly including the impurity scattering. Another difference is that there is a new structure in $(\alpha_{tr}^2F)_{\text{eff}}$ at $\Omega = 34 \text{ cm}^{-1}$ ($\cong 4 \text{ meV}$) as compared to the true α_{tr}^2F spectrum. In Refs. 1 and 2 no new structure was introduced in the effective α^2F due to the variation in $N(\epsilon)$ [except for the

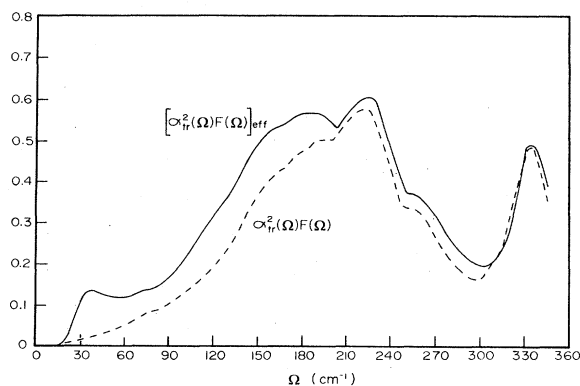


FIG. 4. The effective α_{tr}^2F spectrum (solid line) and the true α_{tr}^2F (dashed line).

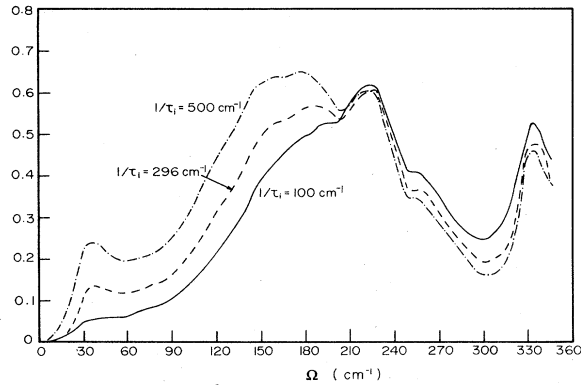


FIG. 5. Effective $\alpha_{tr}^2 F$ spectra for three different impurity scattering parameters.

negative tail at $\Omega \geq \Omega_{max}$ (Ref. 1)]. To illustrate that this new feature in $(\alpha_{tr}^2 F)_{eff}$ is introduced by the impurity contribution to the scattering times with our choice for $N(\epsilon)$, we have calculated and inverted two additional $S'(\omega)$ spectra for $1/\tau_i = 100 \text{ cm}^{-1}$ and $1/\tau_i = 500 \text{ cm}^{-1}$, while keeping the remaining parameters the same as before. The results are shown in Fig. 5. We point out that a larger $1/\tau_i$ would introduce more smearing in the electronic density of states, while we used a fixed $n_s(\epsilon)$ in obtaining all three curves in Fig. 5.

It should be noted that all these effects of a nonconstant $N(\epsilon)$ depend on the actual form of the density of states. For instance, a triangular model for $n_s(\epsilon)$,

$$n_s(\epsilon) = \left[1 - \frac{1}{2\epsilon_c} \epsilon \right] \Theta(\epsilon_c - \epsilon) + 0.5\Theta(\epsilon - \epsilon_c),$$

$$\epsilon_c = 190 \text{ cm}^{-1}$$

where Θ is a step function, gave an $(\alpha_{tr}^2 F)_{eff}$ which was shifted down with respect to $\alpha_{tr}^2 F$ by about 0.05 and, thus, had a negative tail.

Finally we comment that all results obtained for $n_s(\epsilon)$ from Fig. 1 remained qualitatively unchanged when we

performed the calculations with Eqs. (34b) and (35b) which include the renormalization factor $[1 + \bar{\lambda}(\omega)]^{-1/2}$.

IV. CONCLUSIONS

We have generalized Allen's theory of far-infrared absorption in superconductors to the case of nonconstant electronic density of states $N(\epsilon)$. Our numerical calculations using the parameters which fit the far-infrared transmission data on normal thin film of V_3Si (Ref. 11) show an additional frequency dependence in the derivative $S'(\omega)$, due to nonconstant $N(\epsilon)$. As a result of this, if $S'(\omega)$ data were inverted conventionally [i.e., assuming $N(\epsilon) = \text{const}$] the resulting effective $\alpha_{tr}^2 F$ spectrum will contain an extra frequency dependence as compared to the true microscopic EP coupling function. This situation is analogous to the case of superconductive tunneling,^{1,2} but in the case of infrared absorption the effect is dominated by the impurity scattering. We stress that the energy renormalization due to electron-phonon interaction makes the structure in the quasiparticle density of states, which appears in the theory of infrared absorption and, in effect, in the theory of tunneling,^{1,2} much sharper¹⁶ than the structure in the bare band-structure density of states broadened by the disorder scattering.

High-resolution far-infrared absorption measurements on good quality homogeneous $A15$ samples of varying residual resistivities can provide more information about the importance of energy dependence in the band density of states in these materials.

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